

HD74HC153

Dual 4-to-1-line Data Selectors/Multiplexers

REJ03D0577-0200 (Previous ADE-205-451) Rev.2.00 Oct 11, 2005

Description

Information on the data inputs of each multiplexer is selected by the address on the A and B inputs, and is presented on the Y outputs. Each multiplexer possesses a strobe input which enables it when taken to a low logic level. When a high logic level is applied to a strobe input, the output of its associated multiplexer is taken low.

Features

• High Speed Operation: t_{pd} (D to Y) = 13 ns typ ($C_L = 50 \text{ pF}$)

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 2$ to 6 V

• Low Input Current: 1 μA max

• Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74HC153P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	Р	_
HD74HC153FPEL	SOP-16 pin (JEITA)	PRSP0016DH-B (FP-16DAV)	FP	EL (2,000 pcs/reel)

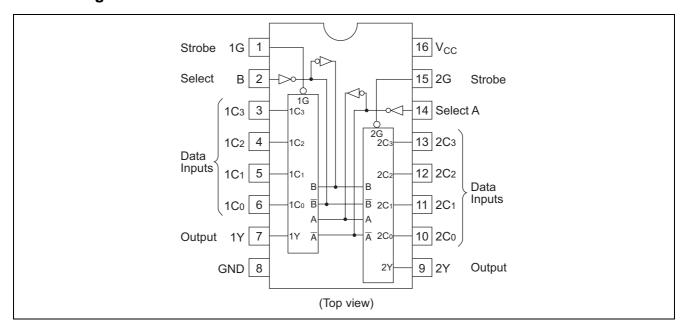
Note: Please consult the sales office for the above package availability.

Function Table

	Inputs							
Se	elect		Strobe	Output				
В	Α	C ₀	C ₁	C ₂	G	Υ		
Х	Х	Х	Х	Х	Х	Н	L	
L	L	L	Х	Х	Х	L	L	
L	L	Н	Х	Х	Х	L	Н	
L	Н	Х	L	Х	Х	L	L	
L	Н	Х	Н	Х	Х	L	Н	
Н	L	Х	Х	L	Х	L	L	
Н	L	Х	Х	Н	Х	L	Н	
Н	Н	Х	Х	Х	L	L	L	
Н	Н	Х	Х	Х	Н	L	Н	

H: High levelL: Low levelX: Irrelevant

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to +7.0	V
Input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Output current	I _{OUT}	±25	mA
DC current drain per V _{CC} , GND	I _{CC} , I _{GND}	±50	mA
DC input diode current	I _{IK}	±20	mA
DC output diode current	I _{OK}	±20	mA
Power dissipation per package	P _T	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	Vcc	2 to 6	V	
Input / Output voltage	V _{IN} , V _{OUT}	0 to V _{CC}	V	
Operating temperature	Та	-40 to 85	°C	
		0 to 1000		V _{CC} = 2.0 V
Input rise / fall time*1	t _r , t _f	0 to 500	ns	V _{CC} = 4.5 V
		0 to 400		$V_{CC} = 6.0 \text{ V}$

Note: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

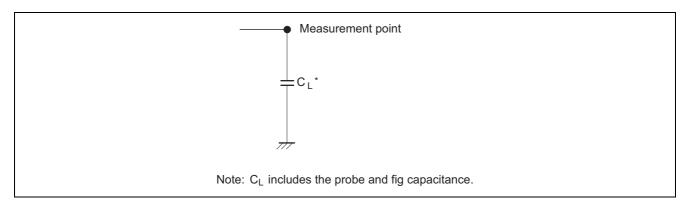
Electrical Characteristics

			Т	a = 25°	С	Ta = -40	to+85°C			
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Con	ditions
Input voltage	V _{IH}	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	_	_	3.15	_			
		6.0	4.2	_	_	4.2	_			
	V_{IL}	2.0	_	_	0.5	_	0.5	V		
		4.5		_	1.35		1.35			
		6.0	_	_	1.8	_	1.8			
Output voltage	V _{OH}	2.0	1.9	2.0	_	1.9	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_			
		6.0	5.9	6.0	_	5.9	_			
		4.5	4.18	_	_	4.13	_			$I_{OH} = -4 \text{ mA}$
		6.0	5.68	_	_	5.63	_			$I_{OH} = -5.2 \text{ mA}$
	V_{OL}	2.0		0.0	0.1		0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 20 \mu A$
		4.5	1	0.0	0.1		0.1			
		6.0	_	0.0	0.1	_	0.1			
		4.5	_	_	0.26	_	0.33			$I_{OL} = 4 \text{ mA}$
		6.0	_	_	0.26	_	0.33			$I_{OL} = 5.2 \text{ mA}$
Input current	lin	6.0			±0.1		±1.0	μΑ	Vin = V _{CC} or GND	
Quiescent supply current	Icc	6.0	_	_	4.0	_	40	μА	Vin = V _{CC} or GN	D, lout = $0 \mu A$

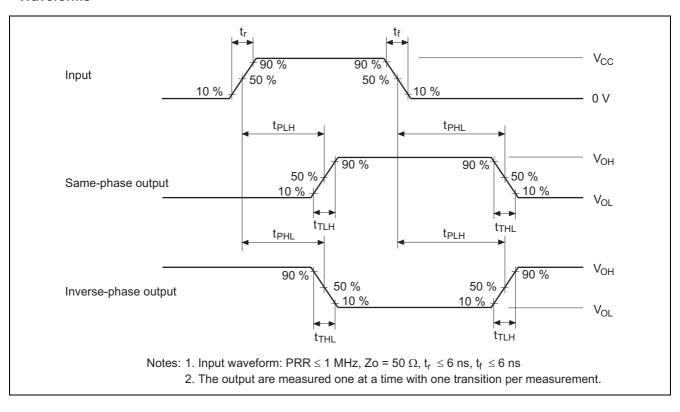
Switching Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

			Т	a = 25°	С	Ta = -40 to +85°C			
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t _{PLH} , t _{PHL}	2.0	_	_	115	_	145	ns	Data to Output Y
time		4.5		13	23	_	29		
		6.0		_	20	_	25		
	t _{PLH} , t _{PHL}	2.0		_	160	_	200	ns	Select to Output Y
		4.5		17	32	_	40		
		6.0		_	27	_	34		
	t _{PLH} , t _{PHL}	2.0		_	95	_	120	ns	Strobe to Output Y
		4.5	_	10	19	_	24		
		6.0		_	16	_	20		
Output rise/fall	t _{TLH} , t _{THL}	2.0		_	75	_	95	ns	
time		4.5		5	15	_	19		
		6.0	_	_	13	_	16		
Input capacitance	Cin	_		5	10	_	10	pF	

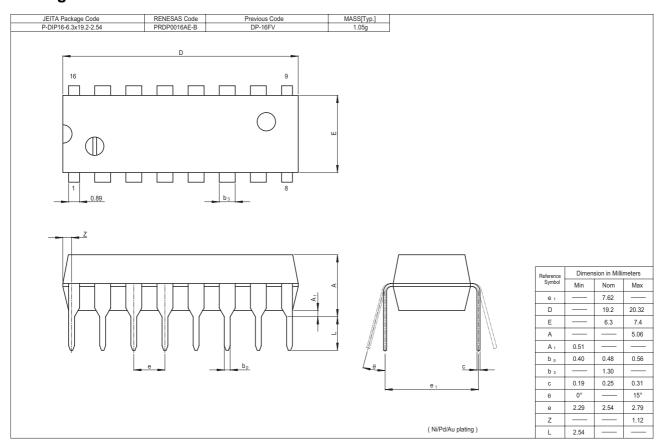
Test Circuit

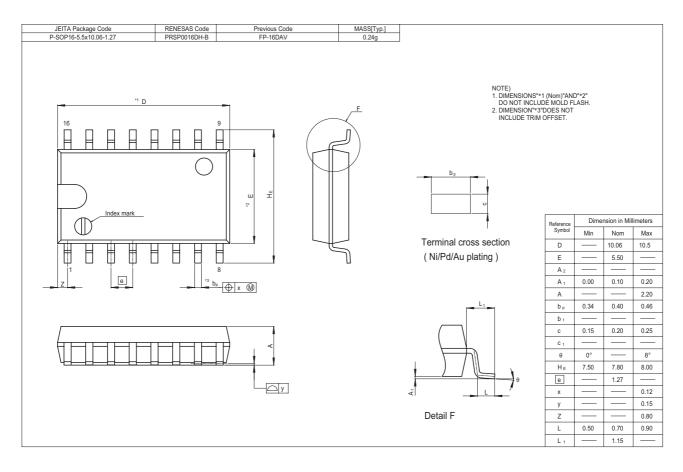


Waveforms



Package Dimensions





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